LM10

LM10 Operational Amplifier and Voltage Reference



Literature Number: SNOSBH4C



LM10

Operational Amplifier and Voltage Reference

General Description

The LM10 series are monolithic linear ICs consisting of a precision reference, an adjustable reference buffer and an independent, high quality op amp.

The unit can operate from a total supply voltage as low as 1.1V or as high as 40V, drawing only $270\mu A$. A complementary output stage swings within 15 mV of the supply terminals or will deliver ± 20 mA output current with ± 0.4 V saturation. Reference output can be as low as 200 mV.

The circuit is recommended for portable equipment and is completely specified for operation from a single power cell. In contrast, high output-drive capability, both voltage and current, along with thermal overload protection, suggest it in demanding general-purpose applications.

The device is capable of operating in a floating mode, independent of fixed supplies. It can function as a remote comparator, signal conditioner, SCR controller or transmitter for

analog signals, delivering the processed signal on the same line used to supply power. It is also suited for operation in a wide range of voltage- and current-regulator applications, from low voltages to several hundred volts, providing greater precision than existing ICs.

This series is available in the three standard temperature ranges, with the commercial part having relaxed limits. In addition, a low-voltage specification (suffix "L") is available in the limited temperature ranges at a cost savings.

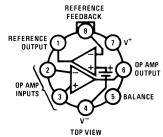
Features

input offset voltage: 2.0 mV (max)
 input offset current: 0.7 nA (max)
 input bias current: 20 nA (max)
 reference regulation: 0.1% (max)
 offset voltage drift: 2µV/°C

■ reference drift: 0.002%/°C

Connection and Functional Diagrams

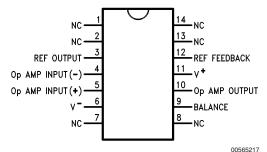
Metal Can Package (H)



00565201

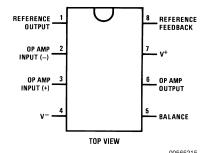
Order Number LM10BH, LM10CH, LM10CLH or LM10H/883 available per SMA# 5962-8760401 See NS Package Number H08A

Small Outline Package (WM)

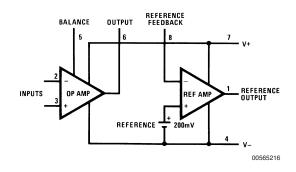


Order Number LM10CWM or LM10CWMX See NS Package Number M14B

Dual-In-Line Package (N)



Order Number LM10CN or LM10CLN See NS Package Number N08E



Absolute Maximum Ratings (Notes 1,

8)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

LM10/LM10B/LM10BL/							
LM10C	LM10CL						

Total Supply Voltage 45V 7V

Differential Input Voltage (Note 2) ±40V ±7V

Power Dissipation (Note 3) internally limited

Output Short-circuit Duration (Note continuous

4)

Storage-Temp. Range -55°C to +150°C

Lead Temp. (Soldering, 10 seconds)

Metal Can 300°C Lead Temp. (Soldering, 10 260°C

seconds) DIP

Vapor Phase (60 seconds) 215°C Infrared (15 seconds) 220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

ESD rating is to be determined.

Maximum Junction Temperature

 LM10
 150°C

 LM10B
 100°C

 LM10C
 85°C

Operating Ratings

Package Thermal Resistance

 θ_{JA}

H Package 150°C/W
N Package 87°C/W
WM Package 90°C/W

 θ_{10}

H Package 45°C/W

Electrical Characteristics

 $T_J=25$ °C, $T_{MIN} \le T_J \le T_{MAX}$ (Boldface type refers to limits over temperature range) (Note 5)

Parameter	Conditions	LM10/LM10B			LM10C			Units
		Min	Тур	Max	Min	Тур	Max	1
Input offset voltage			0.3	2.0		0.5	4.0	mV
				3.0			5.0	mV
Input offset current			0.25	0.7		0.4	2.0	nA
(Note 6)				1.5			3.0	nA
Input bias current			10	20		12	30	nA
				30			40	nA
Input resistance		250	500		150	400		kΩ
		150			115			kΩ
Large signal voltage	V _S =±20V, I _{OUT} =0	120	400		80	400		V/mV
gain	V _{OUT} =±19.95V	80			50			V/mV
	$V_S=\pm 20V$, $V_{OUT}=\pm 19.4V$	50	130		25	130		V/mV
	I _{OUT} =±20 mA (±15 mA)	20			15			V/mV
	V _S =±0.6V (0.65V), I _{OUT} =±2 mA	1.5	3.0		1.0	3.0		V/mV
	V _{OUT} =±0.4V (±0.3V), V _{CM} =-0.4V	0.5			0.75			V/mV
Shunt gain (Note 7)	1.2V (1.3V) ≤V _{OUT} ≤40V,	14	33		10	33		V/mV
	$R_L=1.1 \text{ k}\Omega$							
	0.1 mA≤I _{OUT} ≤5 mA	6			6			V/mV
	1.5V≤V ⁺ ≤40V, R _L =250Ω	8	25		6	25		V/mV
	0.1 mA≤l _{OUT} ≤20 mA	4			4			V/mV
Common-mode	-20V≤V _{CM} ≤19.15V (19V)	93	102		90	102		dB
rejection	V _S =±20V	87			87			dB
Supply-voltage	-0.2V≥V⁻≥-39V	90	96		87	96		dB
rejection	V ⁺ =1.0V (1.1V)	84			84			dB
	1.0V (1.1V) ≤V+≤39.8V	96	106		93	106		dB
	V ⁻ =-0.2V	90			90			dB
Offset voltage drift			2.0			5.0		μV/°C
Offset current drift			2.0			5.0		pA/°C
Bias current drift	T _C <100°C		60			90		pA/°C

Electrical Characteristics (Continued)

 $T_J=25^{\circ}C$, $T_{MIN}\le T_J\le T_{MAX}$ (Boldface type refers to limits over temperature range) (Note 5)

Parameter	Conditions	LM10/LM10B			LM10C			Units
		Min	Тур	Max	Min	Тур	Max	
Line regulation	1.2V (1.3V) ≤V _S ≤40V		0.001	0.003		0.001	0.008	%/V
	0≤I _{REF} ≤1.0 mA, V _{REF} =200 mV			0.006			0.01	%/V
Load regulation	0≤I _{REF} ≤1.0 mA		0.01	0.1		0.01	0.15	%
	V ⁺ –V _{REF} ≥1.0V (1.1V)			0.15			0.2	%
Amplifier gain	0.2V≤V _{REF} ≤35V	50	75		25	70		V/mV
		23			15			V/mV
Feedback sense		195	200	205	190	200	210	mV
voltage		194		206	189		211	mV
Feedback current			20	50		22	75	nA
				65			90	nA
Reference drift			0.002			0.003		%/°C
Supply current			270	400		300	500	μA
				500			570	μΑ
Supply current	1.2V (1.3V) ≤V _S ≤40V		15	75		15	75	μΑ
change								

Electrical Characteristics

 $T_J=25^{\circ}C$, $T_{MIN} \le T_J \le T_{MAX}$ (Boldface type refers to limits over temperature range) (Note 5)

Parameter	Conditions	LM10BL			LM10CL			Units
		Min	Тур	Max	Min	Тур	Max	1
Input offset voltage			0.3	2.0		0.5	4.0	mV
				3.0			5.0	mV
Input offset current			0.1	0.7		0.2	2.0	nA
(Note 6)				1.5			3.0	nA
Input bias current			10	20		12	30	nA
				30			40	nA
Input resistance		250	500		150	400		kΩ
		150			115			kΩ
Large signal voltage	V _S =±3.25V, I _{OUT} =0	60	300		40	300		V/mV
gain	V _{OUT} =±3.2V	40			25			V/mV
	$V_S=\pm 3.25V$, $I_{OUT}=10$ mA	10	25		5	25		V/mV
	V _{OUT} =±2.75 V	4			3			V/mV
	$V_S = \pm 0.6V$ (0.65V), $I_{OUT} = \pm 2$ mA	1.5	3.0		1.0	3.0		V/mV
	$V_{OUT} = \pm 0.4 V$ (±0.3V), $V_{CM} = -0.4 V$	0.5			0.75			V/mV
Shunt gain (Note 7)	1.5V≤V ⁺ ≤6.5V, R _L =500Ω	8	30		6	30		V/mV
	0.1 mA≤l _{OUT} ≤10 mA	4			4			V/mV
Common-mode	-3.25V≤V _{CM} ≤2.4V (2.25V)	89	102		80	102		dB
rejection	V _S =±3.25V	83			74			dB
Supply-voltage	-0.2V≥V⁻≥-5.4V	86	96		80	96		dB
rejection	V ⁺ =1.0V (1.2V)	80			74			dB
	1.0V (1.1V) ≤V ⁺ ≤6.3V	94	106		80	106		dB
	V ⁻ =0.2V	88			74			dB
Offset voltage drift			2.0			5.0		μV/°C
Offset current drift			2.0			5.0		pA/°C
Bias current drift			60			90		pA/°C
Line regulation	1.2V (1.3V) ≤V _S ≤6.5V		0.001	0.01		0.001	0.02	%/V
	0≤I _{REF} ≤0.5 mA, V _{REF} =200 mV			0.02			0.03	%/V

Electrical Characteristics (Continued)

 $T_J=25^{\circ}C$, $T_{MIN}\le T_J\le T_{MAX}$ (Boldface type refers to limits over temperature range) (Note 5)

Parameter	Conditions		LM10BL LM10CL				Units	
		Min	Тур	Max	Min	Тур	Max	
Load regulation	0≤I _{REF} ≤0.5 mA		0.01	0.1		0.01	0.15	%
	V ⁺ –V _{REF} ≥1.0V (1.1V)			0.15			0.2	%
Amplifier gain	0.2V≤V _{REF} ≤5.5V	30	70		20	70		V/mV
		20			15			V/mV
Feedback sense voltage		195	200	205	190	200	210	mV
		194		206	189		211	mV
Feedback current			20	50		22	75	nA
				65			90	nA
Reference drift			0.002			0.003		%/°C
Supply current			260	400		280	500	μΑ
				500			570	μΑ

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Note 2: The Input voltage can exceed the supply voltages provided that the voltage from the input to any other terminal does not exceed the maximum differential input voltage and excess dissipation is accounted for when $V_{IN} < V^-$.

Note 3: The maximum, operating-junction temperature is 150°C for the LM10, 100°C for the LM10B(L) and 85°C for the LM10C(L). At elevated temperatures, devices must be derated based on package thermal resistance.

Note 4: Internal thermal limiting prevents excessive heating that could result in sudden failure, but the IC can be subjected to accelerated stress with a shorted output and worst-case conditions.

Note 5: These specifications apply for $V^- \le V_{CM} \le V^+ - 0.85V$ (1.0V), 1.2V (1.3V) $< V_S \le V_{MAX}$, $V_{REF} = 0.2V$ and $0 \le I_{REF} \le 1.0$ mA, unless otherwise specified: $V_{MAX} = 40V$ for the standard part and 6.5V for the low voltage part. Normal typeface indicates 25°C limits. **Boldface type indicates limits and altered test conditions for full-temperature-range operation**; this is -55° C to 125° C for the LM10, -25° C for the LM10B(L) and 0° C to 70° C for the LM10C(L). The specifications do not include the effects of thermal gradients ($\tau_1 = 20$ ms), die heating ($\tau_2 = 0.2s$) or package heating. Gradient effects are small and tend to offset the electrical error (see curves).

Note 6: For $T_J > 90^{\circ}C$, I_{OS} may exceed 1.5 nA for $V_{CM} = V^{-}$. With $T_J = 125^{\circ}C$ and $V^{-} \le V_{CM} \le V^{-} + 0.1V$, $I_{OS} \le 5$ nA.

Note 7: This defines operation in floating applications such as the bootstrapped regulator or two-wire transmitter. Output is connected to the V⁺ terminal of the IC and input common mode is referred to V⁻ (see typical applications). Effect of larger output-voltage swings with higher load resistance can be accounted for by adding the positive-supply rejection error.

Note 8: Refer to RETS10X for LM10H military specifications.

Definition of Terms

Input offset voltage: That voltage which must be applied between the input terminals to bias the unloaded output in the linear region.

Input offset current: The difference in the currents at the input terminals when the unloaded output is in the linear region.

Input bias current: The absolute value of the average of the two input currents.

Input resistance: The ratio of the change in input voltage to the change in input current on either input with the other grounded. Large signal voltage gain: The ratio of the specified output voltage swing to the change in differential input voltage required to

Shunt gain: The ratio of the specified output voltage swing to the change in differential input voltage required to produce it with the output tied to the V⁺ terminal of the IC. The load and power source are connected between the V⁺ and V⁻ terminals, and input common-mode is referred to the V⁻ terminal.

Common-mode rejection: The ratio of the input voltage range to the change in offset voltage between the extremes.

Supply-voltage rejection: The ratio of the specified supply-voltage change to the change in offset voltage between the extremes.

Line regulation: The average change in reference output voltage over the specified supply voltage range.

Load regulation: The change in reference output voltage from no load to that load specified.

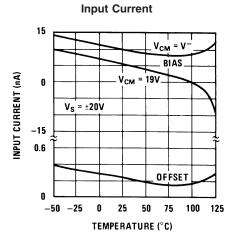
Feedback sense voltage: The voltage, referred to V-, on the reference feedback terminal while operating in regulation.

Reference amplifier gain: The ratio of the specified reference output change to the change in feedback sense voltage required to produce it.

Feedback current: The absolute value of the current at the feedback terminal when operating in regulation.

Supply current: The current required from the power source to operate the amplifier and reference with their outputs unloaded and operating in the linear range.

Typical Performance Characteristics (Op Amp)



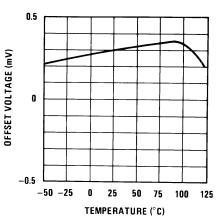
00565218

0 -0.5COMMON-MODE LIMITS (V) -1.0 $\Delta V_{OS} < 0.1 \ mV$ $\Delta I_{OS} < 0.2 \text{ nA}$ 0 < 1 nA $\overline{\Delta V_{OS}} < 0.5 \text{ mV}$ -0.5OS < 2 nA اکا OS < 2 nA کالے < 10 nA -1.0-50 -25 25 50 75 TEMPERATURE (°C)

Common Mode Limits

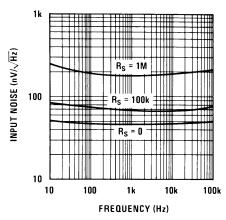
00565219

Output Voltage Drift



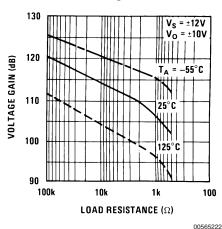
00565220

Input Noise Voltage

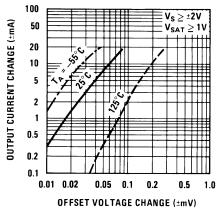


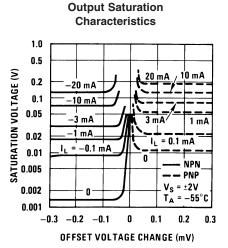
00565221

DC Voltage Gain



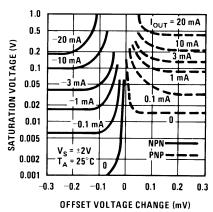
Transconductance





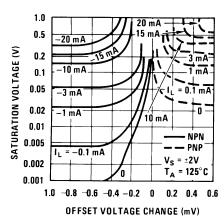
00565224

Output Saturation Characteristics



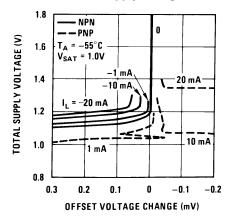
00565335

Output Saturation Characteristics



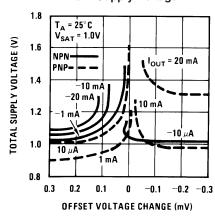
0056522

Minimum Supply Voltage



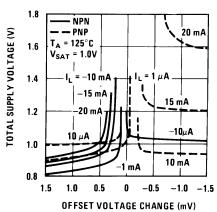
00565227

Minimum Supply Voltage

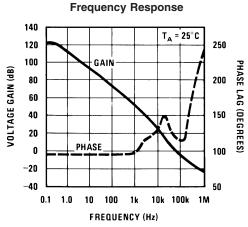


00565228

Minimum Supply Voltage



00565229

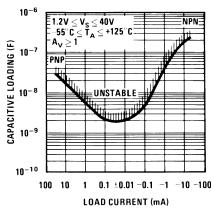


00565230

1k OUTPUT IMPEDANCE (12) 100 10 0.1 100k 1M FREQUENCY (Hz) 00565231

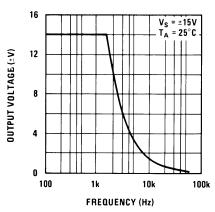
Output Impedance

Typical Stability Range

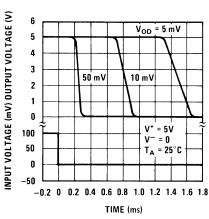


00565232

Large Signal Response



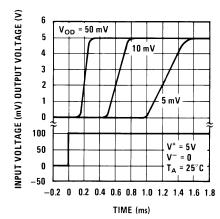
Comparator Response Time For Various Input Overdrives

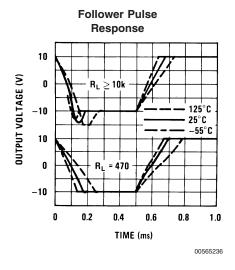


00565234

7

Comparator Response Time For Various Input Overdrives





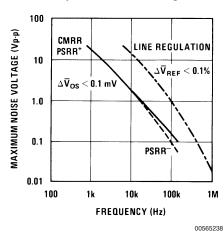
140 V_{REF} = 200 mV 120 PSRR* NOISE REJECTION (48) LINE 100 REGULATION CMRR 80 60 PSRR 40 20 10 100 1k 100k

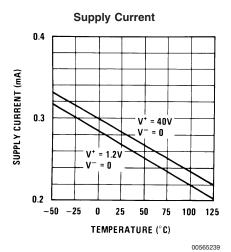
FREQUENCY (Hz)

Noise Rejection

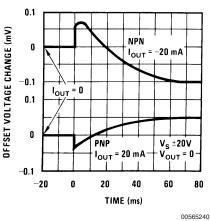
00565237

Rejection Slew Limiting



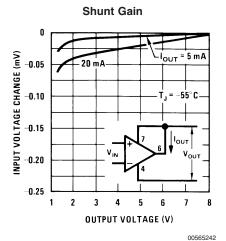


Thermal Gradient Feedback 0.1

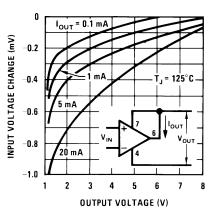


Cross-coupling 0.05 REFERENCE VOLTAGE CHANGE (%) NPN I_{OUT} = -20 mA 0.05 I_{OUT} = 0 PNP 0.05 I_{OUT} = 20 mA V_S ±20V V_{OUT} = 0 -0.05 -20 0 80 20 40 60 TIME (ms)

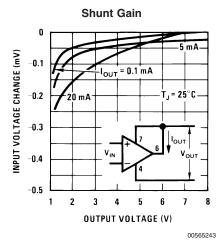
Thermal Gradient



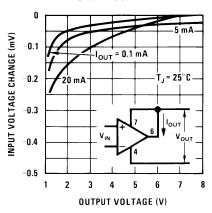
Shunt Gain



00565244

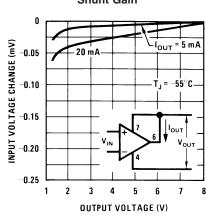


Shunt Gain



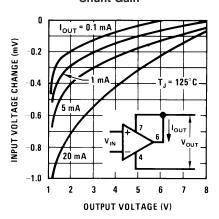
00565243

Shunt Gain

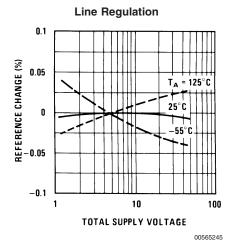


00565242

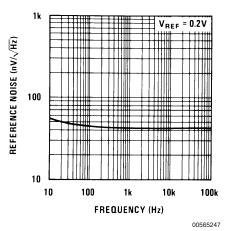
Shunt Gain



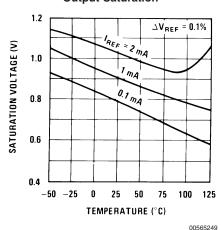
Typical Performance Characteristics (Reference)



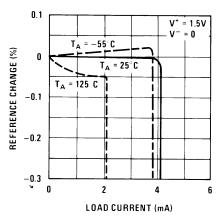
Reference Noise Voltage



Output Saturation

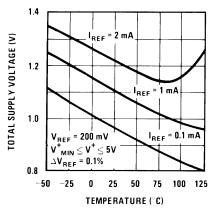


Load Regulation



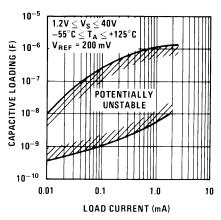
00565246

Minimum Supply Voltage



00565248

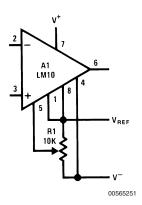
Typical Stability Range



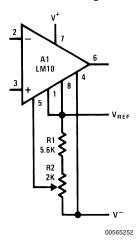
00565250

Op Amp Offset Adjustment

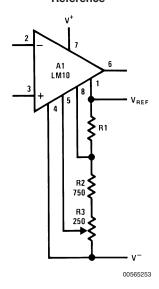
Standard



Limited Range

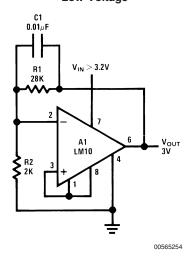


Limited Range With Boosted Reference

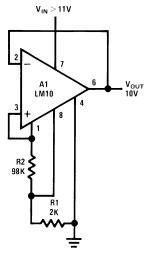


Positive Regulators (Note 9)

Low Voltage

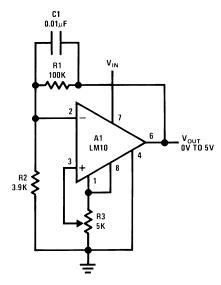


Best Regulation



00565255

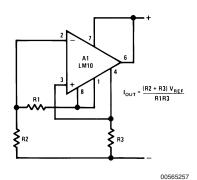
Zero Output



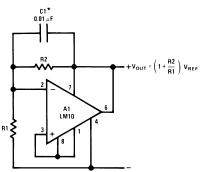
00565256

Note 9: Use only electrolytic output capacitors.

Current Regulator



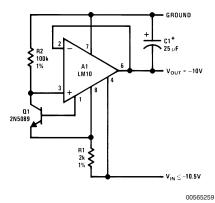
Shunt Regulator



Required For Capacitive Loading

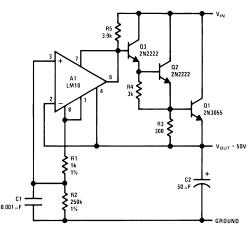
00565258

Negative Regulator

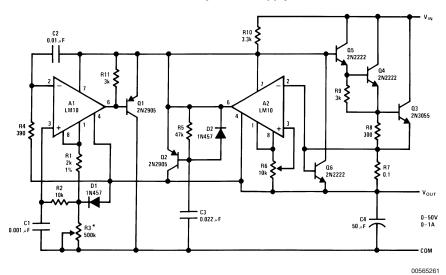


*Electrolytic

Precision Regulator

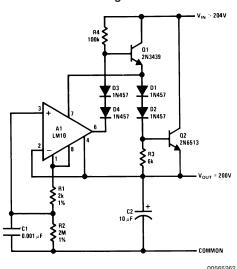


Laboratory Power Supply



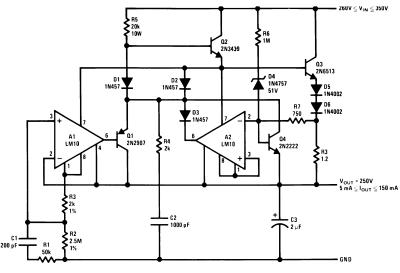
*V_{OUT}=10⁻⁴ R3

HV Regulator



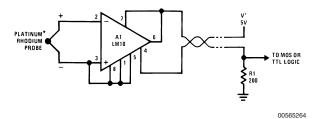
 $V_{OUT} = \frac{R2}{R1} V_{REF}$

Protected HV Regulator



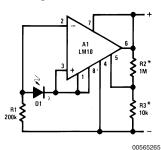
00565263

Flame Detector



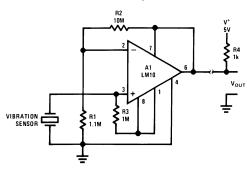
 $^{*}800^{\circ}\text{C}$ Threshold Is Established By Connecting Balance To $\text{V}_{\text{REF}}.$

Light Level Sensor



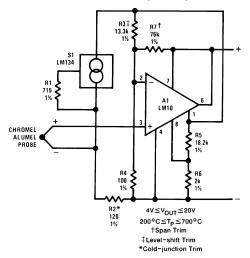
*Provides Hysteresis

Remote Amplifier



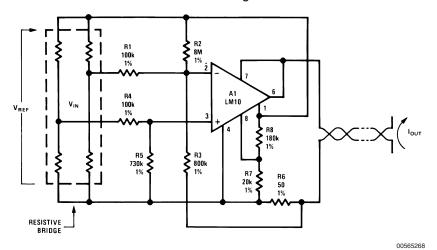
00565266

Remote Thermocouple Amplifier

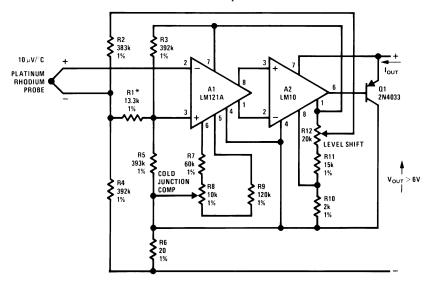


00565267

Transmitter for Bridge Sensor

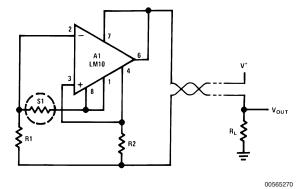


Precision Thermocouple Transmitter



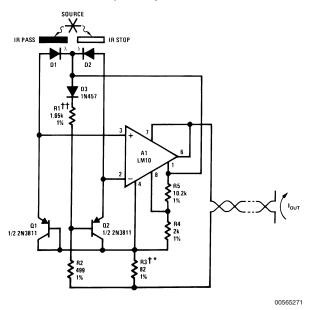
10 mA \leq l $_{OUT}\leq$ 50 mA 500°C \leq T $_{P}\leq$ 1500°C *Gain Trim

Resistance Thermometer Transmitter



16

Optical Pyrometer



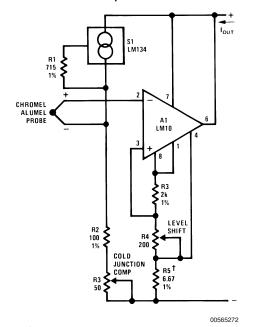
††Level-shift Trim

*Scale Factor Trim

†Copper Wire Wound

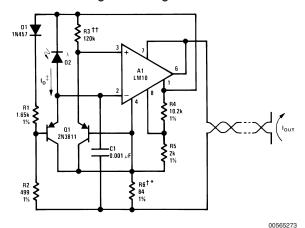
$$\begin{array}{l} 1 \text{ mA} \! \leq \! I_{OUT} \! \leq \! 5 \text{ mA} \\ \\ 0.01 \! \leq \! \frac{I_{D2}}{I_{D1}} \! \leq \! 100 \end{array}$$

Thermocouple Transmitter



 $200^{\circ}\text{C} \le \text{T}_p \le 700^{\circ}\text{C}$ 1 mA $\le \text{I}_{OUT} \le \text{5}$ mA †Gain Trim

Logarithmic Light Sensor



1 mA≤l_{OUT}≤5 mA

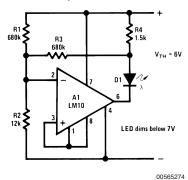
‡50 μA≤I_D≤500 μA

††Center Scale Trim

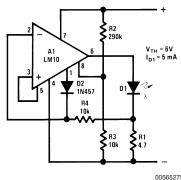
†Scale Factor Trim

*Copper Wire Wound

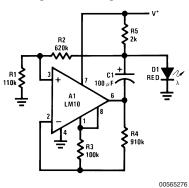
Battery-level Indicator



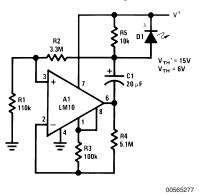
Battery-threshold Indicator



Single-cell Voltage Monitor



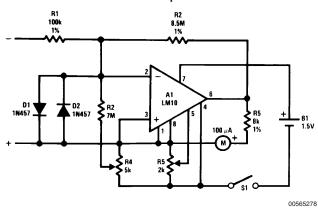
Double-ended Voltage Monitor



Flashes Above 1.2V Rate Increases With Voltage

Flash Rate Increases Above 6V and Below 15V

Meter Amplifier

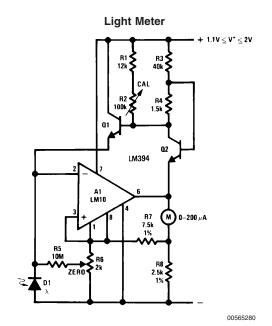


INPUT 10 mV, 100nA FULL-SCALE

Thermometer V* > 1V A1 LM10 R1 732 R2 1% R4 1.5k 1% 00565279

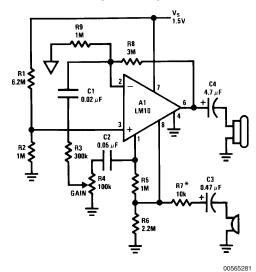
*Trim For Span

†Trim For Zero



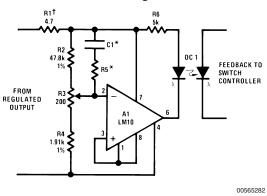
 $1{\le}\lambda/\lambda_0{\le}10^5$

Microphone Amplifier



 $\rm Z_{OUT}\text{-}680\Omega$ @ 5 kHz $\rm A_{V} \!\!\leq\! 1k$ $\rm f_1 \!\!\sim\! 100$ Hz $\rm f_2 \!\!-\! 5$ kHz $\rm R_L \!\!\sim\! 500$ *Max Gain Trim

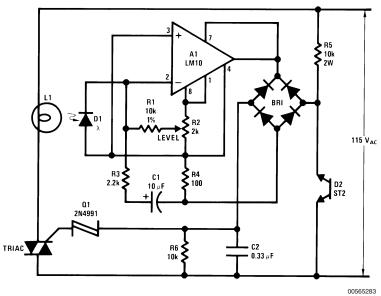
Isolated Voltage Sensor



†Controls "Loop Gain"

*Optional Frequency Shaping

Light-level Controller

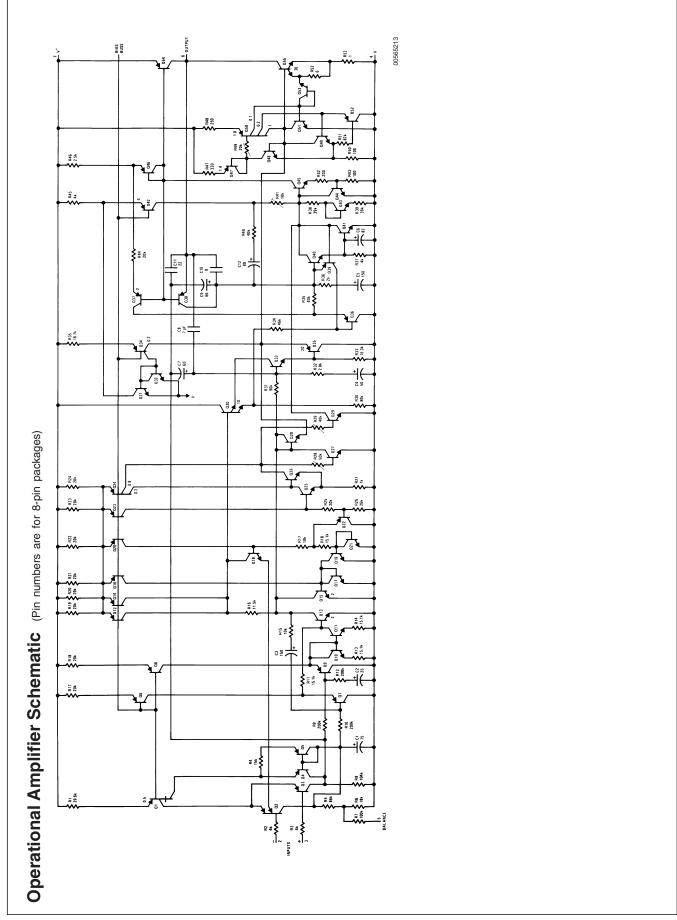


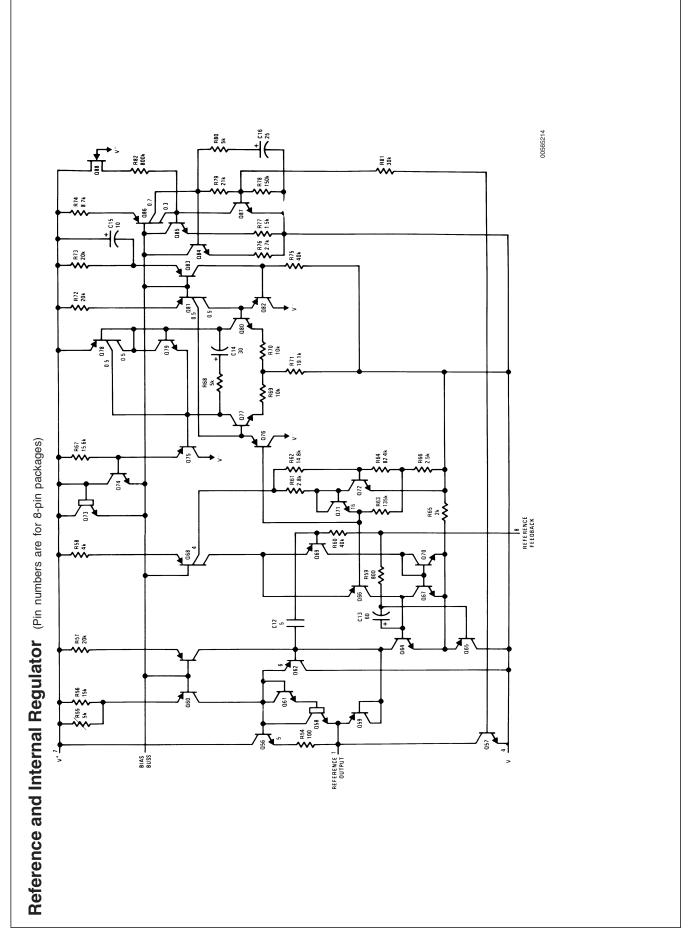
Note 10: Circuit descriptions available in application note AN-211.

Application Hints

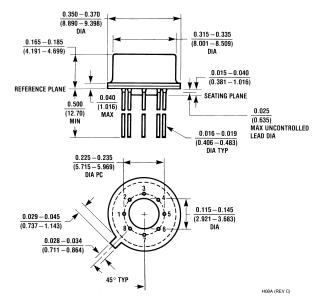
With heavy amplifier loading to V⁻, resistance drops in the V⁻ lead can adversely affect reference regulation. Lead resistance can approach 1Ω . Therefore, the common to the

reference circuitry should be connected as close as possible to the package.

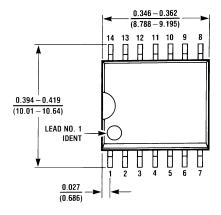


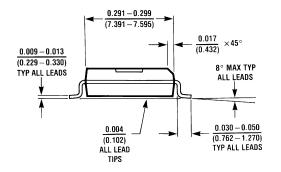


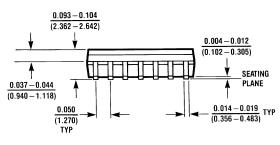
Physical Dimensions inches (millimeters) unless otherwise noted



Metal Can Package (H)
Order Number LM10BH, LM10CH, LM10CLH or LM10H/883
NS Package Number H08A



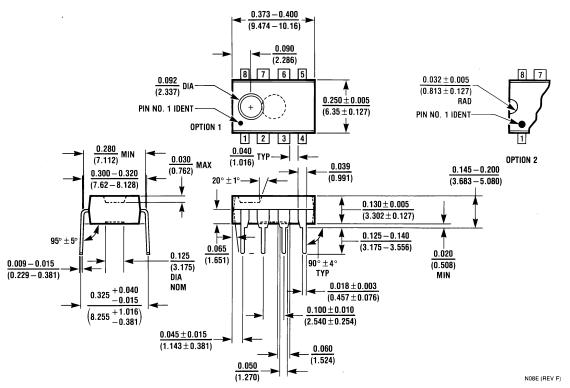




M14B (REV D)

S.O. Package (WM)
Order Number LM10CWM or LM10CWMX
NS Package Number M14B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Dual-In-Line Package (N) Order Number LM10CN or LM10CLN **NS Package Number N08E**

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

BANNED SUBSTANCE COMPLIANCE

National Semiconductor certifies that the products and packing materials meet the provisions of the Customer Products Stewardship Specification (CSP-9-111C2) and the Banned Substances and Materials of Interest Specification (CSP-9-111S2) and contain no "Banned Substances" as defined in CSP-9-111S2.



National Semiconductor Americas Customer Support Center Email: new.feedback@nsc.com

Tel: 1-800-272-9959

www.national.com

National Semiconductor Europe Customer Support Center Fax: +49 (0) 180-530 85 86

Email: europe.support@nsc.com Deutsch Tel: +49 (0) 69 9508 6208 English Tel: +44 (0) 870 24 0 2171 Français Tel: +33 (0) 1 41 91 8790

National Semiconductor Asia Pacific Customer Support Center Email: ap.support@nsc.com **National Semiconductor** Japan Customer Support Center Fax: 81-3-5639-7507 Email: jpn.feedback@nsc.com Tel: 81-3-5639-7560

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products Applications

Audio www.ti.com/audio Communications and Telecom www.ti.com/communications **Amplifiers** amplifier.ti.com Computers and Peripherals www.ti.com/computers dataconverter.ti.com Consumer Electronics www.ti.com/consumer-apps **Data Converters DLP® Products** www.dlp.com **Energy and Lighting** www.ti.com/energy DSP dsp.ti.com Industrial www.ti.com/industrial Clocks and Timers www.ti.com/clocks Medical www.ti.com/medical Interface interface.ti.com Security www.ti.com/security

Logic Space, Avionics and Defense <u>www.ti.com/space-avionics-defense</u>

Power Mgmt power.ti.com Transportation and Automotive www.ti.com/automotive
Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID <u>www.ti-rfid.com</u>
OMAP Mobile Processors www.ti.com/omap

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>

TI E2E Community Home Page <u>e2e.ti.com</u>

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated